# NSN 5962-01-311-9998

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#### **End Application:**

P-3 acft

**Features Provided:** 

Electrostatic sensitive and programmed

## Inclosure Configuration:

Dual-in-line

## Voltage Rating And Type Per Characteristic:

2.4 volts high level output

### Memory Device Type:

Eprom

Shelf Life:

N/a

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Unit Of Measure:

#### Demilitarization:

Yes - demil/mli

Fiig:

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